

LM185-2.5-N/LM285-2.5-N/LM385-2.5-N Micropower Voltage Reference Diode

Check for Samples: LM185-2.5-N, LM285-2.5-N, LM385-2.5-N

FEATURES

- ±20 mV (±0.8%) max. Initial Tolerance (A Grade)
- Operating Current of 20 µA to 20 mA
- 0.6Ω Dynamic Impedance (A Grade)
- **Low Temperature Coefficient**
- Low Voltage Reference—2.5V
- 1.2V Device and Adjustable Device Also Available—LM185-1.2 Series and LM185 Series, respectively

DESCRIPTION

LM185-2.5-N/LM285-2.5-N/LM385-2.5-N micropower 2-terminal band-gap voltage regulator diodes. Operating over a 20 µA to 20 mA current range, they feature exceptionally low dynamic impedance and good temperature stability. On-chip trimming is used to provide tight voltage tolerance. Since the LM-185-2.5-N band-gap reference uses only transistors and resistors, low noise and good long term stability result.

Careful design of the LM185-2.5-N has made the device exceptionally tolerant of capacitive loading, making it easy to use in almost any reference application. The wide dynamic operating range allows its use with widely varying supplies with excellent regulation.

The extremely low power drain of the LM185-2.5-N makes it useful for micropower circuitry. This voltage reference can be used to make portable meters, regulators or general purpose analog circuitry with battery life approaching shelf life. Further, the wide operating current allows it to replace older references with a tighter tolerance part. For applications requiring 1.2V see LM185-1.2.

The LM185-2.5-N is rated for operation over a −55°C to 125°C temperature range while the LM285-2.5-N is rated -40°C to 85°C and the LM385-2.5-N 0°C to 70°C. The LM185-2.5-N/LM285-2.5-N are available in a hermetic TO package and the LM285-2.5-N/LM385-2.5-N are also available in a low-cost TO-92 molded package, as well as SOIC and SOT-23. The LM185-2.5-N is also available in a hermetic leadless chip carrier package.

Connection Diagram

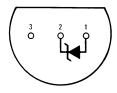


Figure 1. TO-92 Package (Bottom View) See Package Number LP0003A

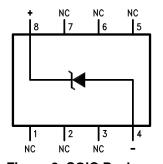


Figure 2. SOIC Package See Package Number D0008A

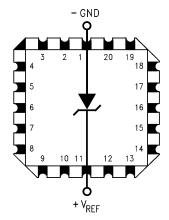


^{*} Pin 3 is attached to the Die Attach Pad (DAP) and should be connected to Pin 2 or left floating.

Figure 3. SOT-23

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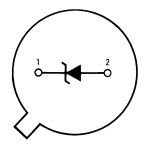


Figure 4. LCCC Leadless Chip Carrier See Package Number NAJ0020A

Figure 5. TO Package (Bottom View) See Package Number NDU0002A



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

ABSOLUTE MAXIMUM RATINGS(1)(2)(3)

Reverse Current			30 mA
Forward Current			10 mA
	LM185-2.5-N		−55°C to + 125°C
Operating Temperature Range ⁽⁴⁾		-40°C to + 85°C	
	LM385-2.5-N		0°C to 70°C
ESD Susceptibility ⁽⁵⁾			2kV
Storage Temperature			−55°C to + 150°C
	TO-92 Package (10 sec.)		260°C
Caldering Information	TO Package (10 sec.)		300°C
Soldering Information	COIC and COT 02 Parkers	Vapor Phase (60 sec.)	215°C
	SOIC and SOT-23 Package	Infrared (15 sec.)	220°C
See http://www.ti.com for other met	hods of soldering surface mount d	evices.	·

- (1) Refer to RETS185H-2.5 for military specifications.
- (2) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but do not ensure specific performance limits. For ensured specifications and test conditions, see the Electrical Characteristics. The ensured specifications apply only for the test conditions listed.
- (3) If Military/Aerospace specified devices are required, please contact the TI Sales Office/Distributors for availability and specifications.
- (4) For elevated temperature operation, T_{J MAX} is:

LM185-N: 150°C LM285-N: 125°C LM385-N: 100°C

See THERMAL CHARACTERISTICS.

(5) The human body model is a 100 pF capacitor discharged through a 1.5 k Ω resistor into each pin.

THERMAL CHARACTERISTICS

over operating free-air temperature range (unless otherwise noted)

	LM185	150°C		
Thermal Resistance	LM285	125°C	6010.8	SOT-23
mermai Resistance	LM385	100°C	SOIC-8	301-23
	TO-92	то		
θ_{ja} (Junction to Ambient)	180°C/W (0.4" Leads)	440°C/W	165°C/W	283°C/W
	170°C/W (0.125" Leads)			
θ _{jc} (Junction to Case)	N/A	80°C/W	N/A	N/A





ELECTRICAL CHARACTERISTICS

			LM385	A-2.5-N		
Parameter	Conditions	Tun	LM385	XX-2.5-N	Units	
Farameter	Conditions	Тур	LM385	Y-2.5-N	(Limits)	
			Tested Limit ⁽²⁾	Design Limit ⁽³⁾		
Reverse Breakdown	I _R = 100 μA	2.500	2.480		V(Min)	
Voltage			2.520		V(Max)	
		2.500		2.470	V(Min)	
				2.530	V(Max)	
Minimum Operating		12	18	20	μΑ	
Current					(Max)	
Reverse Breakdown	$I_{MIN} \le I_R \le 1mA$		1	1.5	mV	
Voltage Change with					(Max)	
Current	1 mA ≤ I _R ≤ 20 mA		10	20	mV	
					(Max)	
Reverse Dynamic	$I_R = 100 \mu A,$	0.2		0.6	Ω	
Impedance	f = 20 Hz			1.5		
Wideband Noise (rms)	I _R = 100 μA	120			μV	
	10 Hz ≤ f ≤ 10 kHz					
Long Term Stability	I _R = 100 μA, T = 1000 Hr,	20			ppm	
	$T_A = 25^{\circ}C \pm 0.1^{\circ}C$					
Average Temperature Coefficient (4)	$I_{MIN} \le I_R \le 20 \text{ mA}$					
	X Suffix		30		ppm/°C	
	Y Suffix		50		(Max)	
	All Others			150		

Parameters identified with boldface type apply at temperature extremes. All other numbers apply at $T_A = T_J = 25^{\circ}C$.

Specified and 100% production tested.

Specified, but not 100% production tested. These limits are not used to calculate average outgoing quality levels. The average temperature coefficient is defined as the maximum deviation of reference voltage at all measured temperatures between the operating T_{MAX} and T_{MIN}, divided by T_{MAX}-T_{MIN}. The measured temperatures are -55°C, -40°C, 0°C, 25°C, 70°C, 85°C, 125°C.



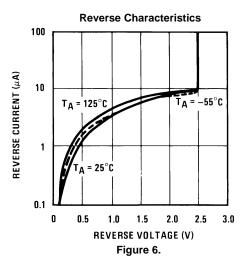
ELECTRICAL CHARACTERISTICS

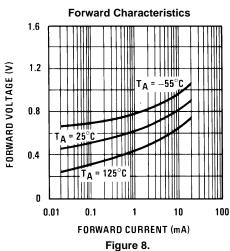
			LM185-2.5-	-N	I MOOF	B-2.5-N			
			LM185BX-2.	LIVISOS	D-2.3-N				
			LM185BY-2.	LM385E	3X-2.5-N	LM385	2 E N		
Parameter	Conditions	Тур	LM285-2.5-			LIVI385	Units		
T drameter	Conditions	1,75	LM285BX-2.	LM385E	3Y-2.5-N			(Limit)	
			LM285BY-2.						
			Tested Limit ⁽¹⁾⁽²⁾	Design Limit ⁽³⁾	Tested Limit ⁽¹⁾	Design Limit ⁽³⁾	Tested Limit ⁽¹⁾	Design Limit ⁽³⁾	
Reverse Breakdown	T _A = 25°C,	2.5	2.462		2.462		2.425		V(Min)
Voltage	$20 \ \mu A \le I_R \le 20 \ mA$		2.538		2.538		2.575		V(Max)
Minimum Operating Current		13	20	30	20	30	20	30	μΑ (Max)
	LM385M3-2.5-N						15	20	
Reverse Breakdown Voltage Change	20 μA ≤ I _R ≤ 1 mA		1	1.5	2.0	2.5	2.0	2.5	mV (Max)
with Current	1 mA ≤ I _R ≤ 20 mA		10	20	20	25	20	25	mV (Max)
Reverse Dynamic	$I_R = 100 \ \mu A$	1							Ω
Impedance	f = 20 Hz								
Wideband Noise (rms)	$I_R = 100 \mu A$, 10 Hz \le f \le 10 kHz	120							μV
Long Term Stability	$I_R = 100 \mu A$,								
	T = 1000 Hr,	20							ppm
	$T_A = 25^{\circ}C \pm 0.1^{\circ}C$								
Average	I _R = 100 μA								
Temperature Coefficient ⁽⁴⁾	X Suffix		30		30				ppm/°C
Commont	Y Suffix		50		50				ppm/°C
	All Others			150		150		150	ppm/°C
									(Max)

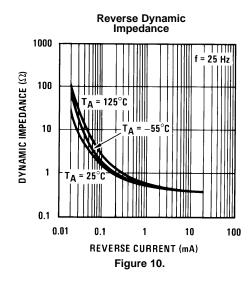
 ⁽¹⁾ Specified and 100% production tested.
 (2) A military RETS electrical specification available on request.
 (3) Specified, but not 100% production tested. These limits are not used to calculate average outgoing quality levels.
 (4) The average temperature coefficient is defined as the maximum deviation of reference voltage at all measured temperatures between the operating T_{MAX} and T_{MIN} , divided by $T_{MAX}-T_{MIN}$. The measured temperatures are $-55^{\circ}C$, $-40^{\circ}C$, $0^{\circ}C$, $25^{\circ}C$, $70^{\circ}C$, $85^{\circ}C$, $125^{\circ}C$.

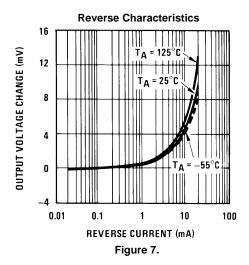


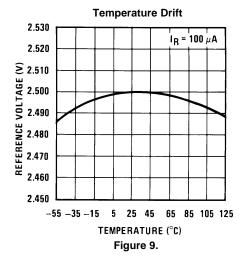
TYPICAL PERFORMANCE CHARACTERISTICS

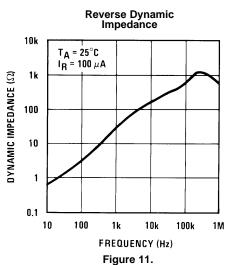






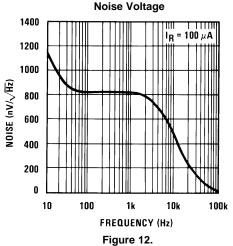


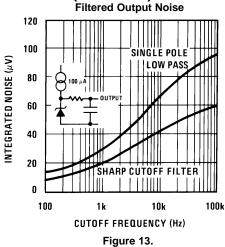


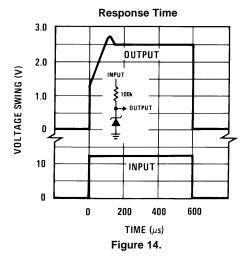




TYPICAL PERFORMANCE CHARACTERISTICS (continued)









APPLICATIONS

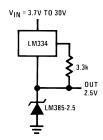


Figure 15. Wide Input Range Reference

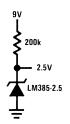
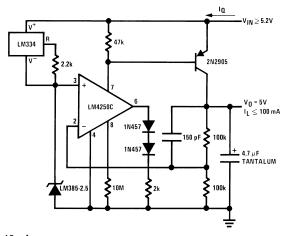


Figure 16. Micropower Reference from 9V Battery

LM385-2.5-N Applications



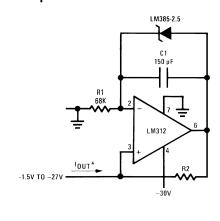


 \bullet I_{OUT} = $\frac{2.5V}{R2}$

 $I_Q \simeq 30 \ \mu A \ standby \ current$

Figure 17. Micropower 5V Reference

PRECISION 1 µA to 1 mA CURRENT SOURCES



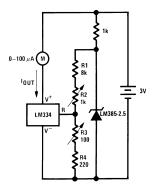
1.5V TO 27V

Figure 18. Micropower 10V Reference

Figure 19.

METER THERMOMETERS





Calibration

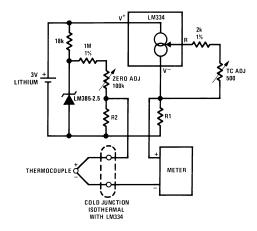
- 1. Short LM385-2.5-N, adjust R3 for I_{OUT} =temp at $1\mu A/^{\circ}K$.
- 2. Remove short, adjust R2 for correct reading in centigrade

Figure 20. 0°C-100°C Thermomemter

Calibration

- 1. Short LM385-2.5-N, adjust R3 for I_{OUT} =temp at 1.8 μ A/°K
- 2. Remove short, adjust R2 for correct reading in °F

Figure 21. 0°F–50°F Thermomemter



Adjustment Procedure

- Adjust TC ADJ pot until voltage across R1 equals Kelvin temperature multiplied by the thermocouple Seebeck coefficient.
- 2. Adjust zero ADJ pot until voltage across R2 equals the thermocouple Seebeck coefficient multiplied by 273.2.

Figure 22. Micropower Thermocouple Cold Junction Compensator

Thermocouple Type ⁽¹⁾	Seebeck Coefficient (_µ V/°C)	R1 (Ω)	R2 (Ω)	Voltage Across R1 @25°C (mV)	Voltage Across R2 (mV)
J	52.3	523	1.24k	15.60	14.32
Т	42.8	432	1k	12.77	11.78
К	40.8	412	953Ω	12.17	11.17
S	6.4	63.4	150Ω	1.908	1.766

(1) Typical supply current 50 μA



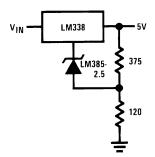
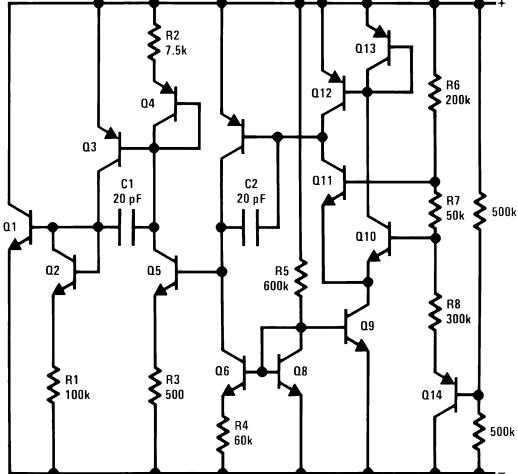


Figure 23. Improving Regulation of Adjstable Regulators

Schematic Diagram



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REVISION HISTORY

Changes from Revision C (March 2013) to Revision D							
•	Changed layout of National Data Sheet to TI format		9				





2-Nov-2013

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
LM185BXH-2.5	ACTIVE	ТО	NDU	2	1000	TBD	Call TI	Call TI	-55 to 125	LM185BXH2.5	Samples
LM185BXH-2.5/NOPB	ACTIVE	ТО	NDU	2	1000	Green (RoHS & no Sb/Br)	POST-PLATE	Level-1-NA-UNLIM	-55 to 125	LM185BXH2.5	Samples
LM185BYH-2.5	ACTIVE	ТО	NDU	2	1000	TBD	Call TI	Call TI	-55 to 125	LM185BYH2.5	Sample
LM185BYH-2.5/NOPB	ACTIVE	ТО	NDU	2	1000	Green (RoHS & no Sb/Br)	POST-PLATE	Level-1-NA-UNLIM	-55 to 125	LM185BYH2.5	Sample
LM285BXM-2.5/NOPB	ACTIVE	SOIC	D	8	95	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	285BX M2.5	Sample
LM285BXMX-2.5/NOPB	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	SN CU SN	Level-1-260C-UNLIM	-40 to 85	285BX M2.5	Sample
LM285BXZ-2.5/NOPB	ACTIVE	TO-92	LP	3	1800	Green (RoHS & no Sb/Br)	SN CU SN	N / A for Pkg Type	-40 to 85	285BX Z2.5	Sample
LM285BYM-2.5/NOPB	ACTIVE	SOIC	D	8	95	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	285BY M2.5	Sample
LM285BYMX-2.5/NOPB	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	285BY M2.5	Sample
LM285BYZ-2.5/NOPB	ACTIVE	TO-92	LP	3	1800	Green (RoHS & no Sb/Br)	SN CU SN	N / A for Pkg Type	-40 to 85	285BY Z2.5	Sample
LM285M-2.5/NOPB	ACTIVE	SOIC	D	8	95	Green (RoHS & no Sb/Br)	SN CU SN	Level-1-260C-UNLIM	-40 to 85	LM285 M2.5	Sample
LM285MX-2.5/NOPB	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	SN CU SN	Level-1-260C-UNLIM	-40 to 85	LM285 M2.5	Sample
LM285Z-2.5/LFT7	ACTIVE	TO-92	LP	3	2000	Green (RoHS & no Sb/Br)	SN CU SN	N / A for Pkg Type		LM285 Z-2.5	Sample
LM285Z-2.5/NOPB	ACTIVE	TO-92	LP	3	1800	Green (RoHS & no Sb/Br)	SN CU SN	N / A for Pkg Type	-40 to 85	LM285 Z-2.5	Sample
LM385BM-2.5/NOPB	ACTIVE	SOIC	D	8	95	Green (RoHS & no Sb/Br)	SN CU SN	Level-1-260C-UNLIM	0 to 70	LM385 BM2.5	Sample
LM385BMX-2.5	NRND	SOIC	D	8	2500	TBD	Call TI	Call TI	0 to 70	LM385 BM2.5	
LM385BMX-2.5/NOPB	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	SN CU SN	Level-1-260C-UNLIM	0 to 70	LM385 BM2.5	Sample
LM385BXM-2.5	NRND	SOIC	D	8	95	TBD	Call TI	Call TI	0 to 70	385BX	





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Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Sample
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5) M2.5	
LM385BXM-2.5/NOPB	ACTIVE	SOIC	D	8	95	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	0 to 70	385BX M2.5	Sampl
LM385BXMX-2.5/NOPB	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	0 to 70	385BX M2.5	Sampl
LM385BXZ-2.5/NOPB	ACTIVE	TO-92	LP	3	1800	Green (RoHS & no Sb/Br)	SN CU SN	N / A for Pkg Type	0 to 70	385BX Z-2.5	Samp
LM385BYM-2.5/NOPB	ACTIVE	SOIC	D	8	95	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	0 to 70	385BY M2.5	Samp
LM385BYMX-2.5/NOPB	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	0 to 70	385BY M2.5	Samp
LM385BYZ-2.5/NOPB	ACTIVE	TO-92	LP	3	1800	Green (RoHS & no Sb/Br)	SN CU SN	N / A for Pkg Type	0 to 70	385BY Z-2.5	Samp
LM385BZ-2.5/LFT7	ACTIVE	TO-92	LP	3	2000	Green (RoHS & no Sb/Br)	SN CU SN	N / A for Pkg Type		LM385 BZ2.5	Samp
LM385BZ-2.5/NOPB	ACTIVE	TO-92	LP	3	1800	Green (RoHS & no Sb/Br)	SN CU SN	N / A for Pkg Type	0 to 70	LM385 BZ2.5	Samp
LM385M-2.5/NOPB	ACTIVE	SOIC	D	8	95	Green (RoHS & no Sb/Br)	SN CU SN	Level-1-260C-UNLIM	0 to 70	LM385 M2.5	Samp
LM385M3-2.5	NRND	SOT-23	DBZ	3	1000	TBD	Call TI	Call TI	0 to 70	R12	
LM385M3-2.5/NOPB	ACTIVE	SOT-23	DBZ	3	1000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	0 to 70	R12	Samp
LM385M3X-2.5	NRND	SOT-23	DBZ	3	3000	TBD	Call TI	Call TI	0 to 70	R12	
LM385M3X-2.5/NOPB	ACTIVE	SOT-23	DBZ	3	3000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	0 to 70	R12	Samp
LM385MX-2.5	NRND	SOIC	D	8	2500	TBD	Call TI	Call TI	0 to 70	LM385 M2.5	
LM385MX-2.5/NOPB	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	SN CU SN	Level-1-260C-UNLIM	0 to 70	LM385 M2.5	Samp
LM385Z-2.5/LFT1	ACTIVE	TO-92	LP	3	2000	Green (RoHS & no Sb/Br)	SN CU SN	N / A for Pkg Type		LM385 Z2.5	Samp
LM385Z-2.5/LFT2	ACTIVE	TO-92	LP	3	2000	Green (RoHS & no Sb/Br)	SN CU SN	N / A for Pkg Type		LM385 Z2.5	Samp
LM385Z-2.5/LFT3	ACTIVE	TO-92	LP	3	2000	Green (RoHS & no Sb/Br)	SN CU SN	N / A for Pkg Type		LM385 Z2.5	Samp



PACKAGE OPTION ADDENDUM

2-Nov-2013

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
LM385Z-2.5/LFT7	ACTIVE	TO-92	LP	3	2000	Green (RoHS & no Sb/Br)	SN CU SN	N / A for Pkg Type		LM385 Z2.5	Samples
LM385Z-2.5/NOPB	ACTIVE	TO-92	LP	3	1800	Green (RoHS & no Sb/Br)	SN CU SN	N / A for Pkg Type	0 to 70	LM385 Z2.5	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free** (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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2-Nov-2013

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION



TAPE DIMENSIONS KO P1 BO W Cavity A0

	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

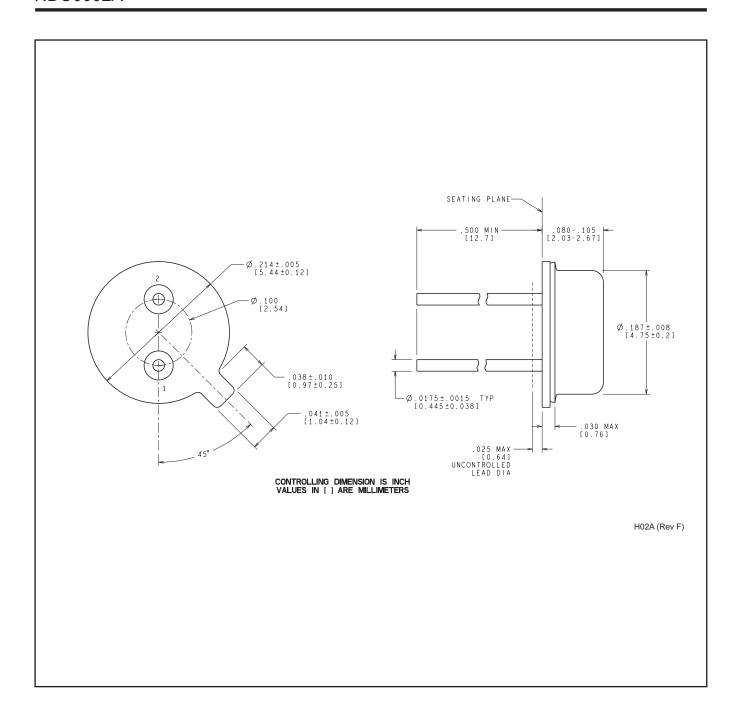
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LM285BXMX-2.5/NOPB	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1
LM285BYMX-2.5/NOPB	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1
LM285MX-2.5/NOPB	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1
LM385BMX-2.5	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1
LM385BMX-2.5/NOPB	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1
LM385BXMX-2.5/NOPB	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1
LM385BYMX-2.5/NOPB	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1
LM385M3-2.5	SOT-23	DBZ	3	1000	178.0	8.4	3.3	2.9	1.22	4.0	8.0	Q3
LM385M3-2.5/NOPB	SOT-23	DBZ	3	1000	178.0	8.4	3.3	2.9	1.22	4.0	8.0	Q3
LM385M3X-2.5	SOT-23	DBZ	3	3000	178.0	8.4	3.3	2.9	1.22	4.0	8.0	Q3
LM385M3X-2.5/NOPB	SOT-23	DBZ	3	3000	178.0	8.4	3.3	2.9	1.22	4.0	8.0	Q3
LM385MX-2.5	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1
LM385MX-2.5/NOPB	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1

www.ti.com 8-Apr-2013



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LM285BXMX-2.5/NOPB	SOIC	D	8	2500	367.0	367.0	35.0
LM285BYMX-2.5/NOPB	SOIC	D	8	2500	367.0	367.0	35.0
LM285MX-2.5/NOPB	SOIC	D	8	2500	367.0	367.0	35.0
LM385BMX-2.5	SOIC	D	8	2500	367.0	367.0	35.0
LM385BMX-2.5/NOPB	SOIC	D	8	2500	367.0	367.0	35.0
LM385BXMX-2.5/NOPB	SOIC	D	8	2500	367.0	367.0	35.0
LM385BYMX-2.5/NOPB	SOIC	D	8	2500	367.0	367.0	35.0
LM385M3-2.5	SOT-23	DBZ	3	1000	210.0	185.0	35.0
LM385M3-2.5/NOPB	SOT-23	DBZ	3	1000	210.0	185.0	35.0
LM385M3X-2.5	SOT-23	DBZ	3	3000	210.0	185.0	35.0
LM385M3X-2.5/NOPB	SOT-23	DBZ	3	3000	210.0	185.0	35.0
LM385MX-2.5	SOIC	D	8	2500	367.0	367.0	35.0
LM385MX-2.5/NOPB	SOIC	D	8	2500	367.0	367.0	35.0





DBZ (R-PDSO-G3)

PLASTIC SMALL-OUTLINE



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. Lead dimensions are inclusive of plating.
- D. Body dimensions are exclusive of mold flash and protrusion. Mold flash and protrusion not to exceed 0.25 per side.
- Falls within JEDEC TO-236 variation AB, except minimum foot length.



D (R-PDSO-G8)

PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AA.





NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

Lead dimensions are not controlled within this area.

Falls within JEDEC TO−226 Variation AA (TO−226 replaces TO−92).

E. Shipping Method:

Straight lead option available in bulk pack only.

Formed lead option available in tape & reel or ammo pack.

Specific products can be offered in limited combinations of shipping mediums and lead options.

Consult product folder for more information on available options.





NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Tape and Reel information for the Formed Lead Option package.

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